

Zibo Seno Electronic Engineering Co., Ltd.



D15XB05-D15XB100



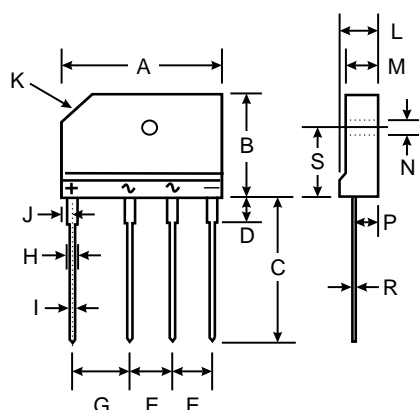
15A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500VRMS
- Low Reverse Leakage Current
- Surge Overload Rating to 240A Peak
- Ideal for Printed Circuit Board Applications
- Plastic Material - UL Flammability Classification 94V-0
- Lead Free Finish/RoHS Compliant

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Molded on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 in-lbs Maximum
- Weight: 6.6 grams (approx)
- Marking: Type Number



| 5S | | |
|----------------------|-----------|-------|
| Dim | Min | Max |
| A | 29.70 | 30.30 |
| B | 19.70 | 20.30 |
| C | 17.00 | 18.00 |
| D | 3.80 | 4.20 |
| E | 7.30 | 7.70 |
| G | 9.80 | 10.20 |
| H | 2.00 | 2.40 |
| I | 0.90 | 1.10 |
| J | 2.30 | 2.70 |
| K | 3.0 X 45° | |
| L | 4.40 | 4.80 |
| M | 3.40 | 3.80 |
| N | 3.10 | 3.40 |
| P | 2.50 | 2.90 |
| R | 0.60 | 0.80 |
| S | 10.80 | 11.20 |
| All Dimensions in mm | | |

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| Characteristic | Symbol | D15XB 05 | D15XB 10 | D15XB 20 | D15XB 40 | D15XB 60 | D15XB 80 | D15XB 100 | Unit |
|---|--|-------------|----------|----------|----------|----------|----------|-----------|------------------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Forward Rectified Output Current @ T _C = 100°C | I _O | 15 | | | | | | | A |
| Non-Repetitive Peak Forward Surge Current, 8.3 ms single half-sine-wave superimposed on rated load (JEDEC method) | I _{FSM} | 240 | | | | | | | A |
| Forward Voltage (per element) @ I _F = 7.5A DC | V _{FM} | 1.05 | | | | | | | V |
| Peak Reverse Current @ T _C = 25°C at Rated DC Blocking Voltage @ T _C = 125°C | I _R | 10 500 | | | | | | | μA |
| I ² t Rating for Fusing (t < 8.3ms) (Note 1) | I ² t | 240 | | | | | | | A ² s |
| Typical Junction Capacitance per Element (Note 2) | C _j | 60 | | | | | | | pF |
| Typical Thermal Resistance, Junction to Case (Note 3) | R _{θJC} | 0.8 | | | | | | | °C/W |
| Operating and Storage Temperature Range | T _j , T _{STG} | -65 to +150 | | | | | | | °C |

- Notes:
1. Non-repetitive, for t > 1ms and < 8.3 ms.
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
 3. Thermal resistance from junction to case per element. Unit mounted on 300 x 300 x 1.6mm copper plate heat sink.

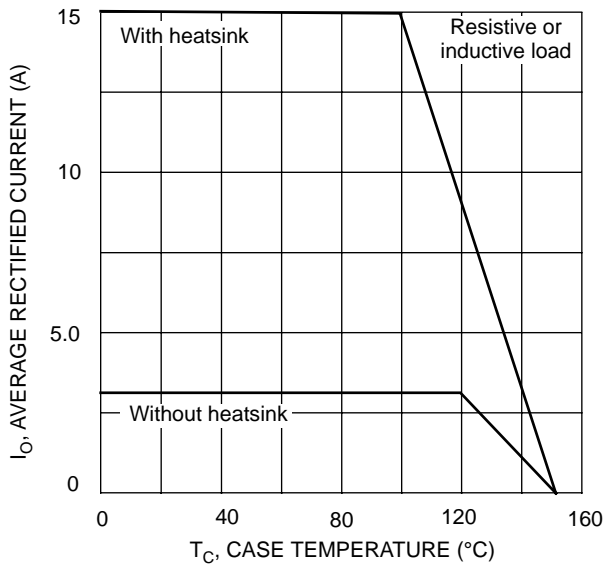


Fig. 1 Forward Current Derating Curve

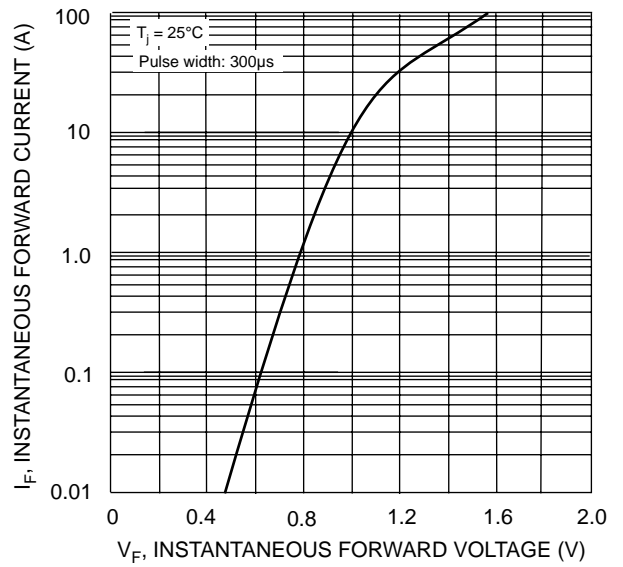


Fig. 2 Typical Forward Characteristics

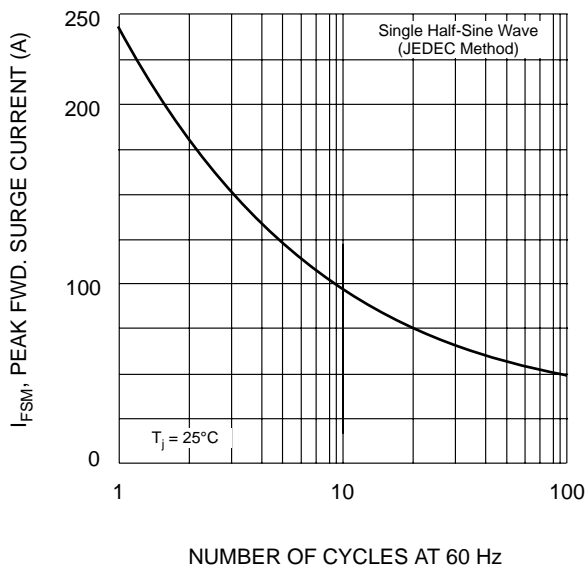


Fig. 3 Maximum Non-Repetitive Surge Current

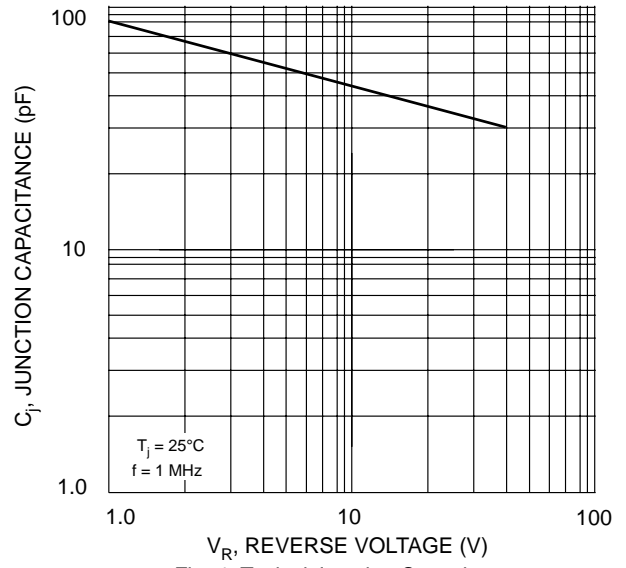


Fig. 4 Typical Junction Capacitance

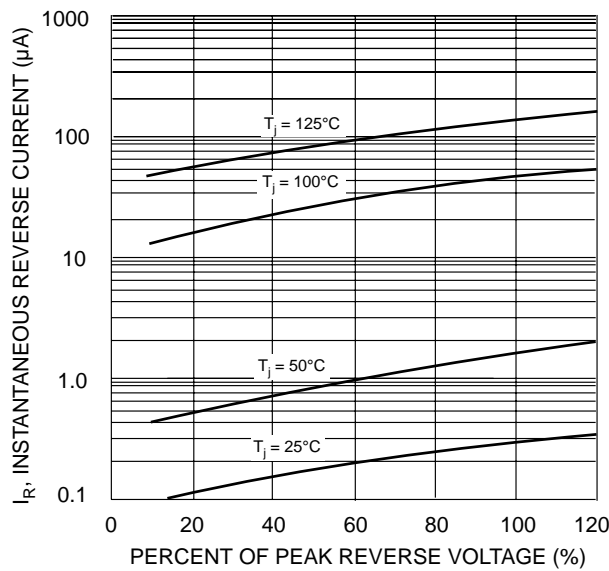


Fig. 5 Typical Reverse Characteristics